MOTOROLA SEMICONDUCTOR TECHNICAL DATA

Advance Information Low Voltage Compander

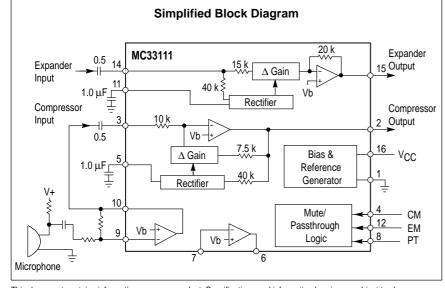
The MC33111 contains two variable gain circuits configured for compressing and expanding the dynamic range of an audio signal. One circuit is configured as an expander, and the other is configured as a compressor. Each circuit has a full wave rectifier to provide average value information to a variable gain cell located in either the input stage or the feedback path. An internal temperature stable bandgap reference provides the necessary precision voltages.

Included in the MC33111 are controls for muting each section independently, and for passthrough of both. Two uncommitted op amps are available for peripheral functions.

The MC33111 will operate from a supply voltage of 3.0 V to 7.0 V, and over a temperature range of -40° to $+85^{\circ}$ C. It is designed to accommodate a 60 dB dynamic range; from -40 dB to +20 dB referenced to 100 mVrms.

Applications include cordless telephone, CBs, walkie-talkies, and most voice RF links, and any application where an improvement in the signal to noise ratio is desired. Other applications include speakerphones and voice activated intercoms, dictating machines, etc.

- Operating Supply Voltage: 3.0 V to 7.0 V
- Output Voltage Swing = 2.8 V_{p-p} with V_{CC} = 3.0 V
- No Precision External Components Required
- 60 dB Dynamic Range Compressed to 30 dB, Re-expandable to 60 dB
- Unity Gain Level set at 100 mVrms
- Attack and Decay Times Adjustable
- Mute and Passthrough Controls
- Two Uncommitted Op Amps
- Temperature Compensated Reference
- Available in Standard DIP and Surface Mount Packages

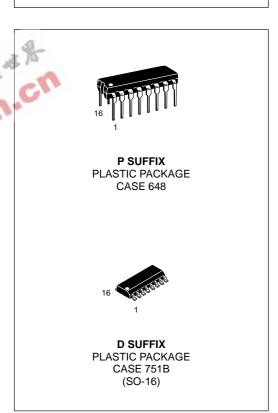


This document contains information on a new product. Specifications and information herein are subject to change without notice. This device contains 329 active transistors.

MC33111

LOW VOLTAGE COMPANDER

SILICON MONOLITHIC INTEGRATED CIRCUIT



TRUTH TABLE

СМ	EM	PT	Function
0	0	0	Normal
1	X	X	Comp. Mute
X	1	X	Expander Mute
0	0	1	Passthrough

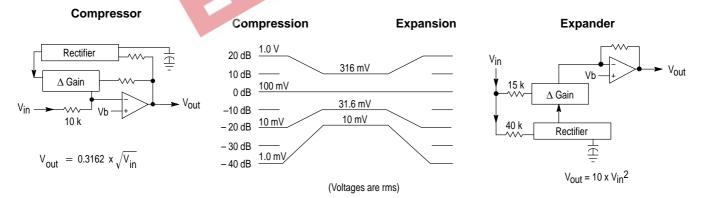
ORDERING INFORMATION

Device	Temperature Range	Package
MC33111D	– 40° to + 85°C	SO-16
MC33111P	- 40 to + 85 C	Plastic DIP

PIN FUNCTION DESCRIPTION

Name	Pin	Description
Ground	1	Connect to a clean power supply ground.
Compressor Output	2	Output of the compressor section.
Compressor Input	3	Compressor input. The input impedance is nominally 10 k Ω . Nominal signal range is 1.0 mVrms to 1.0 Vrms in normal mode, and up to 0.8 Vrms in passthrough mode. Must be capacitor coupled to the signal source.
Compressor Mute	4	A logic high mutes the compressor. A logic low permits normal operation and passthrough.
Compressor Filter	5	Connect an external capacitor to filter the full wave rectifier's output. This capacitor affects attack and decay times, and low frequency accuracy.
Amplifier #1	6, 7	Inverting input (7) and output (6) of an op amp internally referenced to Vb.
Passthrough	8	A logic high sets the gain of both expander and compressor to \approx 0 dB, independent of input level.
Amplifier #2	9, 10	Inverting input (9) and output (10) of an op amp internally referenced to Vb.
Expander Filter	11	Connect an external capacitor to filter the full wave rectifier's output. This capacitor affects attack and decay times, and low frequency accuracy.
Expander Mute	12	A logic high mutes the expander. A logic low permits normal operation and passthrough.
No Connect	13	This pin is not internally connected to anything.
Expander Input	14	Expander input. The input impedance is nominally 10.9 kΩ. Nominal signal range is 10 mVrms to 316 mVrms in normal mode, and up to 1.0 Vrms in passthrough mode. Must be capacitor coupled to the signal source.
Expander Output	15	Output of the expander section.
Vcc	16	Power supply. Connect to a power supply voltage in the range of 3.0 V to 7.0 V. Bypass capacitor should be provided at this pin.

TRANSFER FUNCTIONS



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
V _{CC} Supply Voltage (Pin 16 – Pin 1)	Vcc	-0.5, +12	Vdc
High Input Voltage (Pins 3, 4, 8, 12, 14)	VIH	V _{CC} + 0.5	Vdc
Low Input Voltage (Pins 3, 4, 8, 12, 14)	V _{IL}	- 0.5	Vdc
Output Source Current (Pins 2, 6, 10, 15)	IO+	Self-limiting	mA
Output Sink Current (Pins 2, 6, 10, 15)	IO-	Self-limiting	mA
Storage Temperature	T _{stg}	- 65, + 150	°C

NOTE: Devices should not be operated at these limits. The "Recommended Operating Conditions" provides for actual device operation.

RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Min	Тур	Max	Unit
V _{CC} Supply Voltage	Vcc	3.0		7.0	Vdc
Input Signal Voltage Range (3.0 V < V _{CC} < 7.0 V) Compressor — Normal and Mute Mode — Passthrough Mode Expander — Normal Mode — Mute Mode — Passthrough Mode	V _{in}	0 0 0 0	 - - -	1.3 0.8 0.32 1.3 1.0	Vrms
Frequency Range (± 1.0 dB accuracy)	Fin	0.300	_	10	kHz
Logic Input Voltage Range (Pins 4, 8, 12)	V _{in}	0	_	Vcc	Vdc
Operating Ambient Temperature	TA	- 40	_	+ 85	°C

NOTE: All limits are not necessarily functional concurrently.

ELECTRICAL CHARACTERISTICS ($V_{CC} = 3.6 \text{ V}$, f = 1.0 kHz, $T_A = + 25$ °C, unless noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
COMPRESSOR (Pin 4 = Low unless noted)		•		•	
0 dB Gain (V _{in} = 100 mVrms)	GOC	-1.5	0	1.5	dB
Gain tracking relative to G_{OC} V_{in} = 1.0 Vrms V_{in} = 1.0 mVrms	GTC	9.0 21	10 - 20	11 –19	dB
Passthrough Gain (Pin 8 = High, Pin 4 = Low, V _{in} = 1.0 Vrms)	GPTC	- 2.0	0	1.0	dB
Muting (Δ Gain) with Pin 4 = High (V _{in} = 1.0 Vrms)	GMTC	55	67	_	dB
Max. Output Swing @ Pin 2 (3.0 V < V _{CC} < 7.0 V) Normal Mode Passthrough Mode	V _{out}		1.1 2.3		V _{p-p}
Peak Output Current (3.0 \leq V _{CC} \leq 7.0 V, Normal or Passthrough Modes, V _{in} = Max)	IPK	_	± 4.0	_	mA
Total Harmonic Distoration (V _{in} = 100 mVrms)	THD	_	0.2	1.0	%
Power Supply Rejection @ 1.0 KHz Vin (Pin 3) = 0 Vin (Pin 3) = 10 mVrms Vin (Pin 3) = 1.0 Vrms	PSRR	_ _ _	37 64 72	_ _ _	dB
Attack Time (Capacitor @ Pin 5 = 1.0 μF, per EIA-553) Decay Time (Capacitor @ Pin 5 = 1.0 μF, per EIA-553)	tAT(C) tD(C)	_ _	3.0 14		ms
Input Impedance at Pin 3	Rin	8.0	10	14	kΩ
DC Bias Level (Pin 2) Output DC Shift (V _{in} Changed from 0 to 100 mVrms)	VbIAS	1.4 - 20	Vb 1.6	1.6 2.0	Vdc mVdc
EXPANDER (Pin 12 = Low, unless noted)	•	•		•	•
0 dB Gain (V _{in} = 100 mVrms)	GOE	-1.5	0	1.5	dB
Gain Tracking Relative to G _{OE} $V_{in} = 316 \text{ mVrms}$ $V_{in} = 10 \text{ mVrms}$	GTE	19 – 41	20 - 40	21 - 39	dB
Passthrough Gain (Pin 8 = High, Pin 12 = Low, V_{in} = 1.0 Vrms)	GPTE	-1.0	0	2.0	dB
Muting (Δ Gain) with Pin 12 = High (V_{in} = 0.316 Vrms)	G _{MTE}	60	76	_	dB
Max. Output Swing @ Pin 15 $(3.0 \text{ V} < \text{V}_{CC}$, 7.0 V) Normal Mode Passthrough Mode	V _{out}		2.8 2.8		V _{p-p}
Peak Output Current $\begin{aligned} &\text{V}_{CC} = 3.0 \text{ V, V}_{out} \leq 2.4 \text{ V}_{p\text{-}p} \\ &\text{V}_{CC} = 3.0 \text{ V, V}_{out} = 2.7 \text{ V}_{p\text{-}p} \\ &\text{V}_{CC} \geq 3.6 \text{ V, V}_{out} \leq 2.8 \text{ V}_{p\text{-}p} \end{aligned}$	IPK	_ _ _ _	± 3.5 ±1.0 ± 4.0	_ _ _	mA
Total Harmonic Distoration (V _{in} = 100 mVrms)	THD	_	0.2	1.0	%

ELECTRICAL CHARACTERISTICS (V_{CC} = 3.6 V, f = 1.0 kHz, T_A = + 25°C, unless noted.)

Characteristic	,,	Symbol	Min	Тур	Max	Unit
EXPANDER (Pin 12 = Low, unless noted)				<u> </u>		
Power Supply Rejection @ 1.0 kHz V _{in} (Pin 14) = 0 V _{in} (Pin 14) = 10 mVrms		PSRR	_ _	74 76	_	dB
V _{in} (Pin 14) = 316 mVrms			_	62	_	
Attack Time (Capacitor @ Pin 11 = 1.0 μ F, per EIA-5 Decay Time (Capacitor @ Pin 11 = 1.0 μ F, per EIA-5		^t AT(E) ^t D(E)	_ _	3.0 14	_	ms
Input Impedance at Pin 14		R _{in}	8.0	10.9	14	kΩ
DC Bias Level (Pin 15) Output DC Shift (V _{in} changed from 0 to 100 mVrms)		VbIAS	1.4 - 20	Vb 1.0	1.6 20	Vdc mVdc
LOGIC INPUTS (Pins 4, 8, 12)						
Switching Threshold (3.0 < V _{CC} < 7.0 V)		V _{ST}	_	1.3	_	Vdc
Input Current @ V _{in} = 0 V @ V _{in} = 3.6 V		Rin	_ _	0 55	_	μА
Timing (Vin @ Pins 3 and 14 = 300 mVrms, See Figue Comp. Mute (Pin 4) to Comp. Output Exp. Mute (Pin 12) to Exp. Output	Low-to-High High-to-Low Low-to-High	tCMLH tCMHL tEMLH	4 Th	2.0 3.0 2.0	_ _ _	μs
Passthrough (Pin 8) to Comp. Output	High-to-Low Low-to-High High-to-Low	[†] EMHL [‡] PCLH [†] PCHL	1.C/	3.0 2.0 5.0	_ _ _	
Passthrough (Pin 8) to Exp. Output	Low-to-High High-to-Low	tPELH tPEHL	_ _	6.0 7.0	_ _	
OP AMPS (Pins 6, 7, 9, 10)						
Open Loop Gain		AVOL	_	100	_	dB
Gain Bandwidth		BW	_	300	_	kHz
Input Bias Current @ Pins 7, 9		l _{IB}	_	8.0	_	nA
Max Output Swing @ Pins 6, 10 (3.0 V < V _{CC} < 7.0	V)	V _{out}	_	2.8	_	V _{p-p}
Peak Output Current $V_{CC} = 3.0 \text{ V}, V_{out} \le 2.4 \text{ V}_{p-p}$ $V_{CC} = 3.0 \text{ V}, V_{out} = 2.6 \text{ V}_{p-p}$ $V_{CC} \ge 3.6 \text{ V}, V_{out} \le 2.8 \text{ V}_{p-p}$		IPK	_ _ _	± 3.0 ± 2.0 ± 3.7	_ _ _	mA
Total Harmonic Distoration (V _{Out} = 1.0 Vrms, Unity G	Gain)	THD	_	0.02	0.2	%
MISCELLANEOUS	,				-	
Power Supply Current @ V _{CC} = 3.6 V @ V _{CC} = 7.0 V		Icc		1.5 1.7	2.0 —	mA
Reference Voltage		Vb	_	1.5	_	Vdc
Channel Separation Expander to Compressor (Pin 14 = 316 mVrms @ 1.0 kHz and Pin 3 = (Pin 14 = 100 mVrms (300 Hz < f < 20 kHz),	0 mVrms)	CS	40	70	_	dB
Pin 3 = 100 mVrms @ 1.2 kHz) Compressor to Expander			_	96	_	
(Pin 3 = 1.0 Vrms @ 1.0 kHz and Pin 14 = 0 t (Pin 3 = 100 mVrms (300 Hz < f < 20 kHz),	mVrms)		60	100	_	
Pin 14 = 100 mVrms @ 1.2 kHz)			_	97	_	

TEMPERATURE PERFORMANCE (Typical performance based on device characterization, not guaranteed.)

Characteristic	- 40°C	+25°C	+ 85°C
Power Supply Current @ $V_{CC} = 3.6 \text{ V}$ @ $V_{CC} = 7.0 \text{ V}$	1.2 mA 1.4 mA	1.5 mA 1.7 mA	1.6 mA 1.9 mA
Reference Voltage (Vb)	1.495 V	1.5 V	1.505 V
0 dB Gain (V _{in} = 100 mVrms) — Compressor	0.08 dB	0 dB	- 0.04 dB
0 dB Gain (V _{in} = 100 mVrms) — Expander	0.04 dB	0 dB	- 0.03 dB
Total Harmonic Distortion (V _{in} = 100 mVrms) — Compressor	0.3%	0.2%	0.2%
Total Harmonic Distortion (V _{in} = 100 mVrms) — Expander	0.3%	0.2%	0.16%
Gain Tracking Relative to 0 dB Gain — Compressor V _{in} = 1.0 Vrms V _{in} = 1.0 mVrms	10.8 dB -19.95 dB	10 dB - 20 dB	10 dB - 20.1 dB
Gain Tracking Relative to 0 dB Gain — Expander V _{in} = 316 mVrms V _{in} = 10 mVrms	18.6 dB - 40.2 dB	20 dB - 40 dB	19.95 dB - 39.9 dB
Muting (Δ Gain) with Pin 4 = High (V _{in} = 1.0 Vrms) — Compressor	68 dB	67 dB	66 dB
Muting (Δ Gain) with Pin 12 = High (Vin = 0.316 Vrms) — Expander	76 dB	76 dB	75 dB

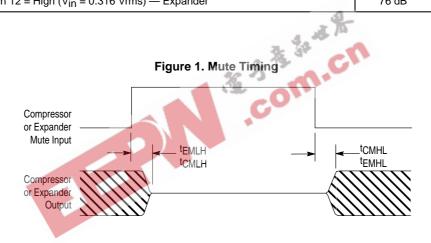
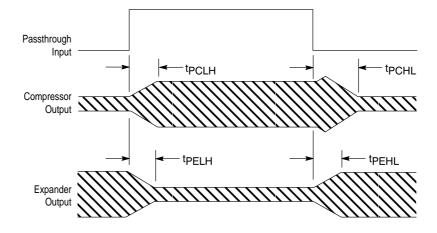
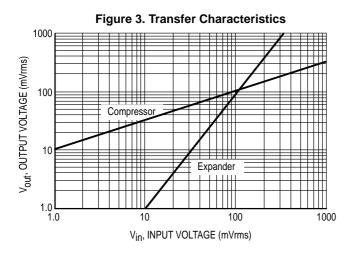
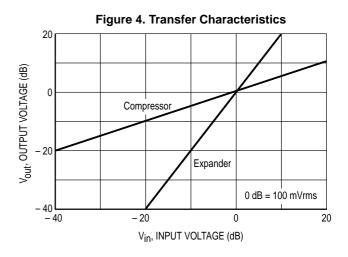
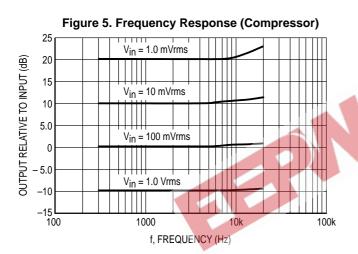


Figure 2. Passthrough Timing









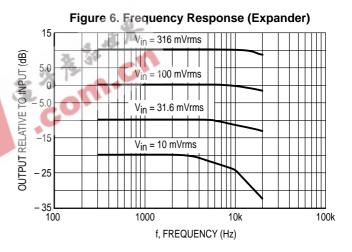
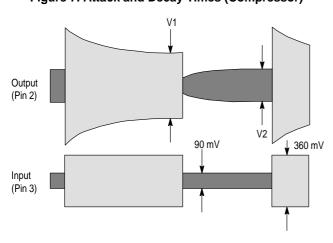
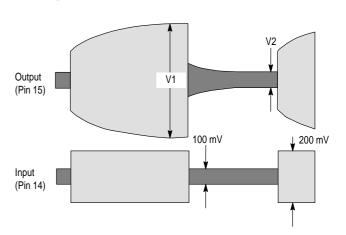


Figure 7. Attack and Decay Times (Compressor)

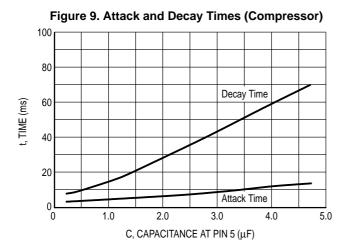


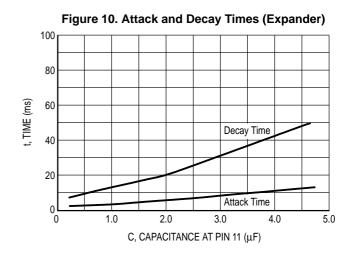
Attack Time = Time to 1.5 x V1 from input increase. Decay Time = Time to 0.75 x V2 from input decrease. Test per EIA-553.

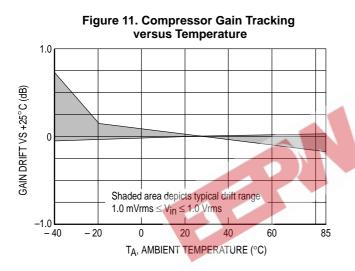
Figure 8. Attack and Decay Times (Expander)

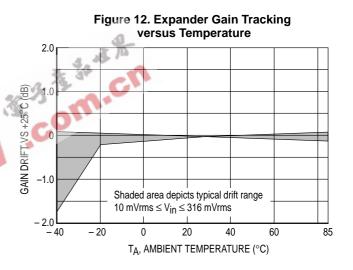


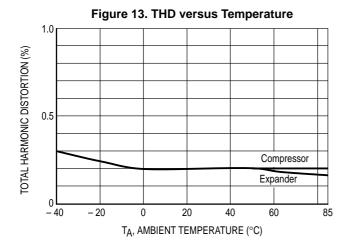
Attack Time = Time to 0.57 x V1 from input increase. Decay Time = Time to 1.5 x V2 from input decrease. Test per EIA-553.

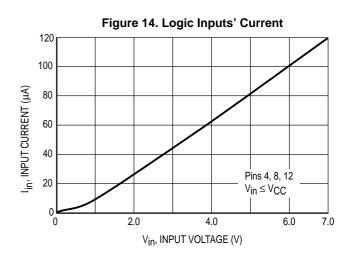












FUNCTIONAL DESCRIPTION

Introduction

The MC33111 compander (COMpressor and exPANDER) is composed of two variable gain circuits which provide compression and expansion of a signal's dynamic range. The compressor will take a signal with a 60 dB dynamic range (1.0 mV to 1.0 Vrms), and reduce that to a 30 dB dynamic range (10 mV to 316 mV) by attenuating strong signals, while amplifying low level signals. The expander does the opposite in that the 30 dB signal range is increased to a dynamic range of 60 dB by amplifying strong signals and attenuating low level signals. The 0 dB level is internally set at 100 mVrms — that is the signal level which is neither amplified nor attenuated. Both circuits contain the necessary precision full wave rectifier, variable gain cell, and temperature compensated references required for accurate and stable performance.

Both the compressor and expander can be muted independently by the use of Pins 4 and 12, respectively. A minimum of 55 dB of muting is guaranteed for the compressor, and 60 dB for the expander. A passthrough function (Pin 8) is provided which sets both sections to unity gain, regardless of input level.

Two uncommitted op amps are provided which can be used for perpherial functions. Each is internally biased at Vb (\approx +1.5 V), and has a bandwidth of \approx 300 kHz.

NOTE: All dB values mentioned in this data sheet, unless otherwise noted, are referenced to 100 mVrms.

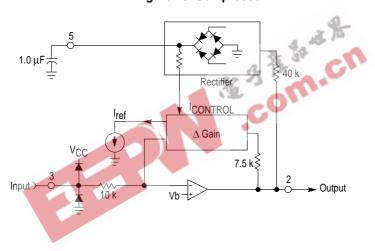


Figure 15. Compressor

Compressor

The compressor is a noninverting amplifier with a fixed input resistor and a variable gain cell in its feedback path as shown in Figure 15.

The amplifier output is sampled by the precision rectifier which, in turn, supplies a DC signal (ICONTROL), representative of the rectifier's AC signal, to the variable gain cell. The reference current (IRFF) is an internally generated precision current. The effective impedance of the variable gain cell varies with the ratio of the two currents, and decreases as ICONTROL increases, thereby providing compression. The output is related to the input by the following equation (Vin and Vout are rms volts):

$$V_{out} = 0.3162 \text{ x} \sqrt{V_{in}}$$
 (1) In terms of dB levels, the relationship is:

$$Vo(dB) = 0.5 \times Vi(dB)$$
 (2)

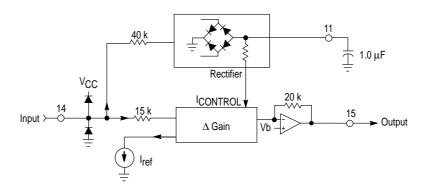
where 0 dB = 100 mVrms (See Figures 3 and 4).

The input and output are internally biased at Vb ($\approx +1.5 \text{ V}$), and must therefore be capacitor coupled to external circuitry. Pin 3 input impedance is nominally 10 k Ω (\pm 20%), and the maximum functional input signal is listed in the Recommended Operating Conditions table. Bias currents required by the op amp and the variable gain cell are internally supplied. Due to clamp diodes at the input (to VCC and ground), the input signal must be maintained between the supply rails. If the input signal goes more than 0.5 V above VCC or below ground, excessive currents will flow, and distortion will show up at the output and possibly in other parts of the circuit.

When AC signals are not present at the input, the variable gain cell will attempt to set a very high gain to comply with Equation 2. An internal clamp limits the maximum gain to ≈ 26 dB to prevent instabilities.

The output of the rectifier is filtered by the capacitor at Pin 5, which, in conjunction with an internal 20 k resistor, provides the time constant for the attack and decay times. The attack and decay times listed in the Electrical Characteristics were determined using the test procedure defined in EIA-553. Figure 9 indicates how the times vary with the capacitor value. If the attack and decay times are decreased using a smaller capacitor, performance at low frequencies will degrade.

Figure 16. Expander



Expander

The expander is an noninverting amplifier with a fixed feedback resistor and a variable gain cell in its input path as shown in Figure 16.

The input signal is sampled by the precision rectifier which, in turn, supplies a DC signal (ICONTROL), representative of the AC input signal, to the variable gain cell. The reference current (IREF) is an internally generated precision current. The effective impedance of the variable gain cell varies with the ratio of the two currents, and decreases as ICONTROL increases, thereby providing expansion. The output is related to the input by the following equation (V_{in} and V_{out} are rms volts):

$$V_{\text{out}} = 10 \text{ x } (V_{\text{in}})^2 \tag{3}$$

$$Vo(dB) = 2.0 \times Vi(dB) \tag{4}$$

where 0 dB = 100 mVrms (See Figures 3 and 4).

The input and output are internally biased at Vb (\approx +1.5 V), and must therefore be capacitor coupled to external circuitry. The input impedance at Pin 14 is nominally 10.9 k Ω (\pm 20%), and the maximum functional input signal is listed in the Recommended Operating Conditions table. Bias currents required by the op amp and the variable gain cell are internally supplied. Due to clamp diodes at the input (to VCC and ground), the input signal must be maintained between the supply rails. If the input signal goes more than 0.5 V above VCC or below ground, excessive currents will flow, and distortion will show up at the output, and possibly in other parts of the circuit.

The output of the rectifier is filtered by the capacitor at Pin 11, which, in conjunction with an internal 20 k resistor, provides the time constant for the attack and decay times. The attack and decay times listed in the Electrical Characteristics were determined using the test procedure defined in EIA-553. Figure 10 indicates how the times vary with the capacitor value. If the attack and decay times are decreased by using a smaller capacitor, performance at low frequencies will degrade.

Op Amps

The two op amps (at Pins 6, 7, 9, and 10) are identical and can be used for peripheral functions, such as a microphone amplifier, buffer, filter, etc. They have an open loop gain of ≈ 100 dB, and a bandwidth of ≈ 300 kHz. The noninverting inputs are internally biased at Vb ($\approx +1.5$ V). The inverting inputs (Pins 7, 9) require a bias current of ≈ 8.0 nA, which flows **into** the pin. The outputs can typically supply a maximum of 3.7 mA load current (see Electrical Characteristics).

NOTE: If an op amp is unused, its output MUST be tied to its input (Pin 6 to 7 and/or 9 to 10). Leaving an input open can affect other portions of the IC.

Logic Inputs

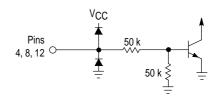
The three inputs (Pins 4, 8, 12) provide for muting and passthrough functions for the compressor and expander according to the following truth table:

- Alb.		-	
CM (Pin 4)	EM (Pin 12)	PT (Pin 8)	Function
0	0	0	Normal Operation
1	Х	Х	Compressor Mute
X	1	Х	Expander Mute
0	0	1	Passthrough

The logic section permits the compressor and expander to be muted independently. The Passthrough control affects both sections simultaneously, but only if the Mute inputs are at a logic level 0. If both the Passthrough and a Mute input are asserted, the Mute will override the Passthrough. The logic controls do not affect the two uncommitted op amps in any way.

Figure 17 depicts a typical logic input stage configuration, and Figure 14 indicates the typical input current. The inputs' threshold is \approx +1.3 V, independent of VCC. An open input is equivalent to a logic low, but good design practices dictate that inputs should never be left open. The inputs must be kept within the range of VCC and GND. If an input is taken more than 0.5 V above VCC or below GND excessive currents will flow, and the device's operation will be distorted.

Figure 17. Logic Input Stage



Power Supply

The MC33111 requires a supply voltage between 3.0 V and 7.0 V, and a nominal current of \approx 1.6 mA. The supply voltage should be well filtered and free of ripple. A minimum of 4.7 μF in parallel with a 0.01 μF capacitor is recommended for filtering and RF bypass.

Vb is an internally generated reference set at \approx +1.5 V, and is used internally as an AC ground. It is not available directly at any pins, but can be obtained as a buffered reference from either op amp by connecting the op amp as a follower.

APPLICATION INFORMATION

Typical Application Circuit

Figure 18 indicates a typical implementation of the MC33111 compander. The following points apply:

- a) The values shown adjacent to some components are based on the expected use of the IC:
 - The input capacitors (Pins 3 and 14) provide a 3.0 dB rolloff of ≈ 30 Hz, a decade below the nominal voiceband.
 - The rectifier capacitors provide attack and decay times as indicated in the Electrical Tables.
- b) The values for the unlabeled components are application dependent:
 - The components around the op amps depend on their use.
 - The value of the capacitors at the compressor and

- expander outputs depend on the circuit to which they are connected.
- c) If either the compressor or expander is not used, its input **must** not be left open. It can be connected to ground either through a capacitor, or directly to ground.
- d) The two op amps can be used for any purpose which suits the application. The indicated use of the one op amp as a microphone amplifier is only an example.
- e) If an op amp is not used, its output and input **must** be connected together. Do not leave Pin 7 or Pin 9 open.
- f) The logic inputs (Pins 4, 8, 12) are TTL/CMOS compatible. The logic high voltage must not exceed the V_{CC} voltage on the MC33111. Any unused input should be connected to ground and not left open.

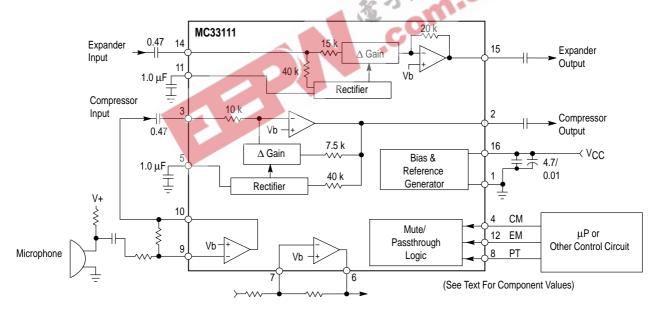


Figure 18. Typical Application

Signal-To-Noise Improvement

Among the basic reasons for the original development of compander type circuits was to improve the signal-to-noise ratio of long distance communications circuits, and of voice circuits which are transmitted over RF links (CBs, walkie-talkies, cordless phones, etc.). Since much of the interfering noise heard at the receiving end of a transmission is due to noise picked up, for example, in the airway portion of the RF link, the compressor was developed to increase the low-level signals at the transmitting end. Then any noise picked up in the RF link would be a smaller percentage of the transmitted signal level. At the receiving end, the signal is

then expanded back to is original level, retaining the same high signal-to-noise ratio. While the above explanation indicates it is not necessary to attenuate strong signals (at the transmitting end), a benefit of doing this is the reduced dynamic range which must be handled by the system transmitter and receiver. The MC33111 was designed for a two-to-one compression and expansion, i.e. a 60 dB dynamic signal is compressed to a 30 dB dynamic range, transmitted to the receiving end, and then expanded back to a 60 dB dynamic range.

The MC33111 compander is not limited to RF or long distance telephony applications. It can be used in any system requiring either an improved signal-to-noise ratio, or a reduced dynamic range. Such applications include telephones, speakerphones, tape recorders, wireless microphones, digital recording, and many others.

Power Supplies, Grounding

The PC board layout, and the quality of the power supplies and the ground system **at the IC** are very important in order to obtain proper operation. Noise, from any source, coming into the device on V_{CC} or ground, can cause a distorted output, or incorrect gain levels.

VCC must be decoupled to the appropriate ground **at the IC** (within 1″ max.) with a 4.7 μF capacitor and a 0.01 μF ceramic. A tantalum capacitor is recommended for the larger value if very high frequency noise is present, since electrolytic capacitors simply have too much inductance at those frequencies. The quality of the power supply voltage should be checked at the IC with a high frequency scope. Noise spikes (always present if digital circuits are near this IC) can easily exceed 400 mV, and if they get into the IC, the output can have noise or distortion. Noise can be reduced by inserting resistors and/or inductors between the supply and the IC.

If switching power supplies are used, there will be spikes of 0.5 V or greater at frequencies of 50 kHz – 1.0 MHz. These spikes are generally more difficult to reduce because of their greater energy content. In extreme cases, a 3-terminal regulator (e.g., MC78L05ACP), with appropriate high frequency filtering, should be used and dedicated to the analog portion of the circuit.

The ripple content of the supply should not allow its magnitude to exceed the values in the Recommended Operating Conditions table.

The PC board tracks supplying V_{CC} and ground to the MC33111 should preferably not be at the tail end of the bus distribution, after passing through a maze of digital circuitry. The analog circuitry containing the MC33111 should be close to the power supply, or the connector where the supply voltages enter the board. If V_{CC} is supplying considerable current to other parts of the board, then it is preferable to have dedicated lines directly to the MC33111 and associated circuitry.

PC Board Layout

Although this device is intended for use in the audio frequency range, the various amplifiers have a bandwidth of $\approx 300~\text{kHz}$, and can therefore oscillate at frequencies outside the voiceband should there be excessive stray capacitance or other unintended feedback loops. A solid ground plane is strongly recommended to minimize coupling of any digital noise into the analog section. Use of wire wrapped boards should definitely be avoided.

Since many applications of the MC33111 compander involve voice transmission over RF links, care must be taken in the design of the product to keep RF signals out of the MC33111 and associated circuitry. This involves proper layout of the PC boards and the physical arrangement of the boards, shielding, proper RF ground, etc.

DEFINITIONS

Attack Time — The settling time for a circuit after its input signal has been increased.

Attenuation — A decrease in magnitude of a communication signal, usually expressed in dB.

Bandwidth — The range of information carrying frequencies of a communication system.

Channel Separation — The ability of one circuit to reject outputting signals which are being processed by another circuit. Also referred to as crosstalk rejection, it is usually expressed in dB.

Compander — A contraction of the words compressor and expander. A compander is composed of two circuits, one of each kind.

Compressor — A circuit which compresses, or reduces, the dynamic range of a signal by attenuating strong signals and amplifying low level signals.

dB — A power or voltage measurement unit, referred to another power or voltage. It is generally computed as:

10 x log (P_1/P_2) for power signals, and 20 x log (V_1/V_2) for voltage signals.

dBm — An indication of signal power. 1.0 mW across 600 Ω , or 0.775 Vrms, is typically defined as 0 dBm for telecom applications. Any voltage level is converted to dBm by:

 $dBm = 20 \times log (Vrms/0.775), or$ $<math>dBm = [20 \times log (Vrms)] + 2.22.$

dBrn — Indicates a dBm measurement relative to 1.0 pW power level into 600 Ω . Generally used for noise measurements, 0 dBm = -90 dBm.

dBrnC — Indicates a dBrn measurement using a C-message weighting filter.

Decay Time — The settling time for a circuit after its input signal has been decreased.

Expander — A circuit which expands, or increases the dynamic range of a signal by amplifying strong signals and attenuating low level signals.

Gain — The change in signal amplitude (increase or decrease) after passing through an amplifier, or other circuit stage. Usually expressed in dB, an increase is a positive number, and a decrease is a negative number.

Mute — Reducing the level of an audio signal, generally so that it is inaudible. Partial muting is used in some applications.

Passthrough — Bypassing the compression and/or expansion function by setting the gain to a fixed value (usually unity). This is usually employed when data, rather than voice, is to be transmitted without attenuation.

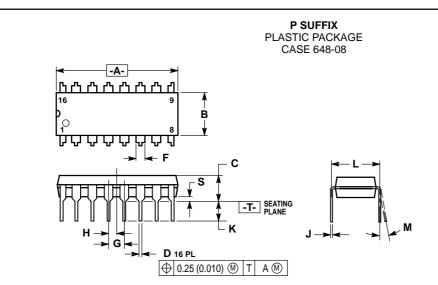
Power Supply Rejection Ratio — The ability of a circuit to reject outputting noise, or ripple, which is present on the power supply lines. PSRR is usually expressed in dB.

Signal to Noise Ratio — The ratio of the desired signal to unwanted signals (noise) within a defined frequency range. The larger the number, the better.

Voiceband — That portion of the audio frequency range used for transmission in the telephone system. Typically it is 300-3400 Hz.

Zero dB Point — The signal level which has its amplitude unchanged by a compressor or expander.

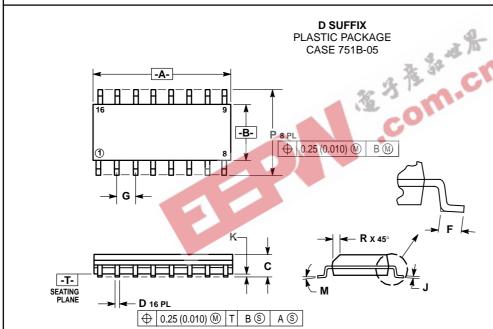
OUTLINE DIMENSIONS



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEADS WHEN 3.
- FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.070	1.02	1.77	
G	0.100) BSC	2.54 BSC		
Н	0.050) BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10°	
S	0.020	0.040	0.51	1.01	



- DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050	BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
М	0°	7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (A) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

Literature Distribution Centers:

USA: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036.

EUROPE: Motorola Ltd.; European Literature Centre; 88 Tanners Drive, Blakelands, Milton Keynes, MK14 5BP, England.

JAPAN: Nippon Motorola Ltd.; 4-32-1, Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan.

ASIA PACIFIC: Motorola Semiconductors H.K. Ltd.; Silicon Harbour Center, No. 2 Dai King Street, Tai Po Industrial Estate, Tai Po, N.T., Hong Kong.

